TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

## TD62304P,TD62304AP,TD62304F,TD62304AF TD62305P,TD62305AP,TD62305F,TD62305AF

#### 7CH LOW ACTIVE DARLINGTON SINK DRIVER

The TD62304P/AP/F/AF and TD62305P/AP/F/AF are non-inverting transistor arrays, which are comprised of eight NPN darlington buffer-transistor output stages and PNP input stages.

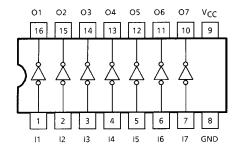
These devices can be operated by source input voltage and are suitable for operations with a 5-V general purposed logic IC such as 5-V TTL, 5-V CMOS and 5-V Microprocessor which have sink current output drivers.

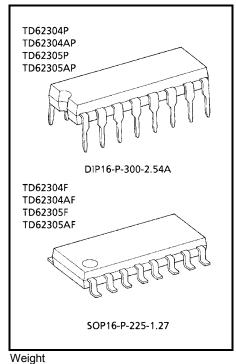
Please observe the thermal condition for using.

#### **FEATURES**

- Output current (single output) 500 mA (Max.)
- High sustaining voltage 35 V (TD62304P/F, 62305P/F) 50 V (TD62304AP/AF, 62305AP/AF) (Min.)
- Low level active input
- Input compatible with 5-V TTL and 5-V CMOS
- Package type-P, AP: DIP-16 pin
- Package type-F, AF: SOP-18 pin

#### **PIN CONNECTION (TOP VIEW)**

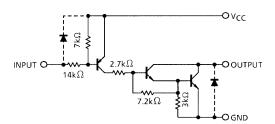




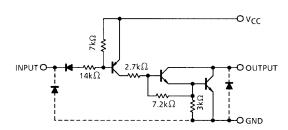
DIP16-P-300-2.54A: 1.11 g (Typ.) SOP16-P-225-1.27: 0.16 g (Typ.)

#### **SCHEMATICS (EACH DRIVER)**

#### TD62034P/AP/F/AF



#### TD62305P/AP/F/AF



Note: The input and output parasitic diodes cannot be used as clamp diodes.



## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTICS		SYMBOL	RATING	UNIT	
Supply Voltage		V <sub>CC</sub>	-0.5~7.0	V	
	P, F		-0.5~35	V	
Output Sustaining Voltage	AF	V <sub>CE</sub> (SUS)	-0.5~50		
	AP		-0.5~50		
Output Current		lout	500	mA / ch	
Input Voltage		V <sub>IN</sub>	-22~V <sub>CC</sub> +0.5	V	
		V IN	-0.5~7 (Note 1)	v	
Input Current		I <sub>IN</sub>	-10	mA	
	Р		1.0	W	
Power Dissipation	AP	$P_{D}$	1.47		
	F, AF		0.625 (Note 2)		
Operating Temperature	Р	т	-30~75	°C	
Operating remperature		T <sub>opr</sub>	-40~85	J	
Storage Temperature		T <sub>stg</sub>	-55~150	°C	

Note 1: TD62305P / AP / F / AF

Note 2: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)



# RECOMMENDED OPERATING CONDITIONS (Ta = -40~85°C and Ta = -30~75°C for only Type-P)

CHARACTERISTIC		SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT	
Supply Voltage		V <sub>CC</sub>	_	4.5	5.0	5.5	V	
Output Sustaining Voltage  P, F  AF  AP		P, F			0	_	35	V
		AF	V <sub>CE</sub> (SUS)	_	0	_	50	
		AP			0	_	50	
Output Current				DC 1 Circuit	0	_	350	
		Р		T <sub>pw</sub> = 25 ms, duty = 10% 7 circuits	0	_	300	
		4.0	l <sub>OUT</sub>	T <sub>pw</sub> = 25 ms, duty = 10% 7 circuits	0	_	350	mA / ch
		AP		T <sub>pw</sub> = 25 ms, duty = 20% 7 circuits	0	_	200	
Input Voltage ———	TD62304P	/AP/F/AF	\/		-20	_	V <sub>CC</sub>	V
	TD62305P	/AP/F/AF	V <sub>IN</sub>	_	0	_	5.5	
Power Dissipation		Р		_	_	_	0.44	W
		AP	$P_{D}$	_	_	_	0.52	
		F, AF		(Note 1)	_	_	0.325	

Note 1: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

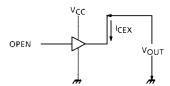
## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

CHARACTE	ERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN	TYP.	MAX	UNIT
Output Leakage Current	P/F	I <sub>CEX</sub>	1	V <sub>CC</sub> = 5.5 V V <sub>IN</sub> = 0 V	V <sub>OUT</sub> = 35 V Ta = 75°C		_	-100	μΑ
					V <sub>OUT</sub> = 50 V Ta = 85°C				
Output Saturation Voltage		V <sub>CE (sat)</sub>	2	V <sub>CC</sub> = 4.5 V I <sub>OUT</sub> = 350 mA	V <sub>IN</sub> = V <sub>IN</sub> (ON) MAX.	_	1.4	2.0	٧
Input Current	(Output On)	I <sub>IN</sub> (ON)	3	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0.4 V			-0.32	-0.45	mA
				V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = −20 V		I	_	-2.6	
	(Output Off)	I <sub>IN (OFF)</sub>	4	_		_	_	-40	μΑ
Input Voltage (Output On)	TD62304	V <sub>IN</sub> (ON)	5	_		-	_	V <sub>CC</sub> -2.8	٧
	TD62305					_	_	V <sub>CC</sub> -3.7	
Supply Current	(Output On)	I <sub>CC</sub> (ON)	6	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0 V		_	17	22	mA
Supply Current	(Output Off)	I <sub>CC (OFF)</sub>	6	V <sub>CC</sub> = V <sub>IN</sub> = 5.5 V		_	_	100	μΑ
Turn-On Delay	P, F	t <sub>ON</sub>	- 7	V <sub>CC</sub> = 5 V, C <sub>L</sub> = 15 pF	V <sub>OUT</sub> = 35 V R <sub>L</sub> = 87.5 Ω		0.1	_	- µs
	AP, AF				V <sub>OUT</sub> = 50 V R <sub>L</sub> = 125 Ω	_			
Turn-Off Delay	P, F	toss			V <sub>OUT</sub> = 35 V R <sub>L</sub> = 87.5 Ω		3	_	
	AP, AF	tOFF			V <sub>OUT</sub> = 50 V R <sub>L</sub> = 125 Ω		3		

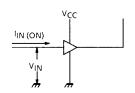
# <u>TOSHIBA</u>

#### **TEST CIRCUIT**

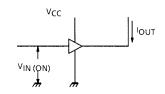
## 1. I<sub>CEX</sub>



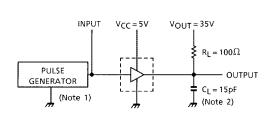
#### 3. I<sub>IN (ON)</sub>



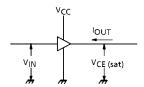
## 5. V<sub>IN</sub> (ON)



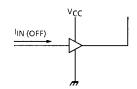
#### 7. ton, toff



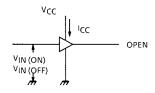
#### 2. hfe, VCE (sat)

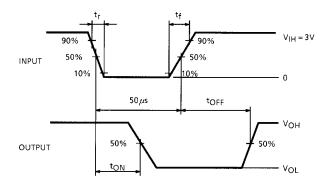


#### 4. I<sub>IN (OFF)</sub>



#### 6. Icc





Note 1: Pulse Width 50  $\mu$ s, duty cycle 10% Output impedance 50  $\Omega$ ,  $t_f \le 10$  ns,  $t_f \le 5$  ns

Note 2: C<sub>L</sub> includes probe and jig capacitance.

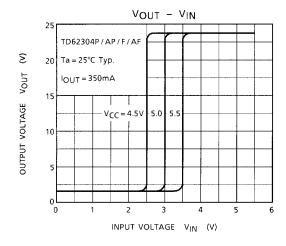
#### **PRECAUTIONS for USING**

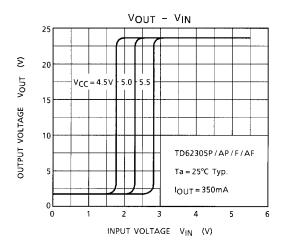
This IC does not include built-in protection circuits for excess current or overvoltage.

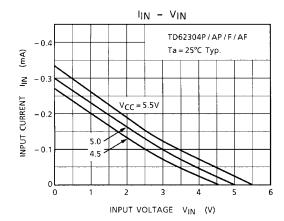
If this IC is subjected to excess current or overvoltage, it may be destroyed.

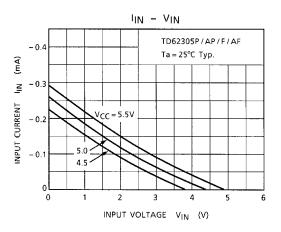
Hence, the utmost care must be taken when systems which incorporate this IC are designed. Utmost care is necessary in the design of the output line, VCC and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

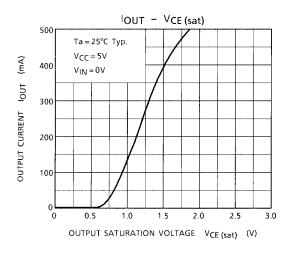
4

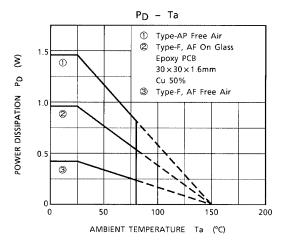


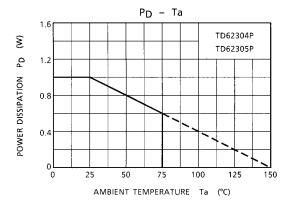








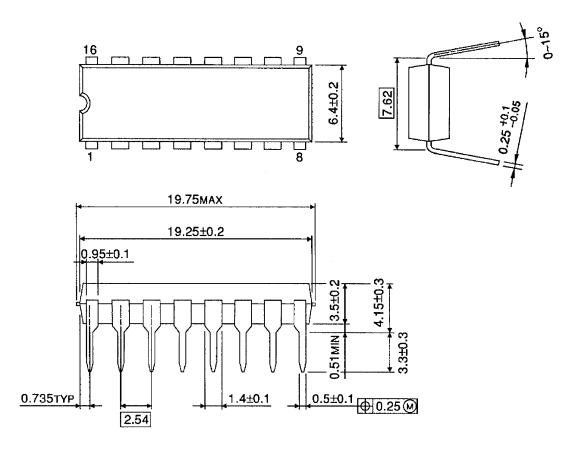




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#### **PACKAGE DIMENSIONS**

DIP16-P-300-2.54A Unit : mm

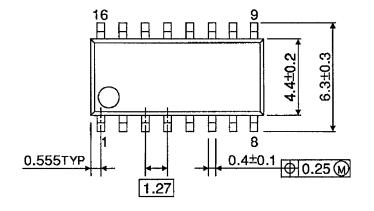


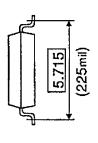
Weight: 1.11 g (Typ.)

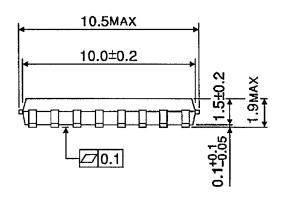
#### **PACKAGE DIMENSIONS**

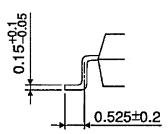
SOP16-P-225-1.27

Unit: mm









Weight: 0.16 g (Typ.)

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000707EBA

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